

## Silicon NPN Power Transistors

## 2SC5101

**DESCRIPTION**

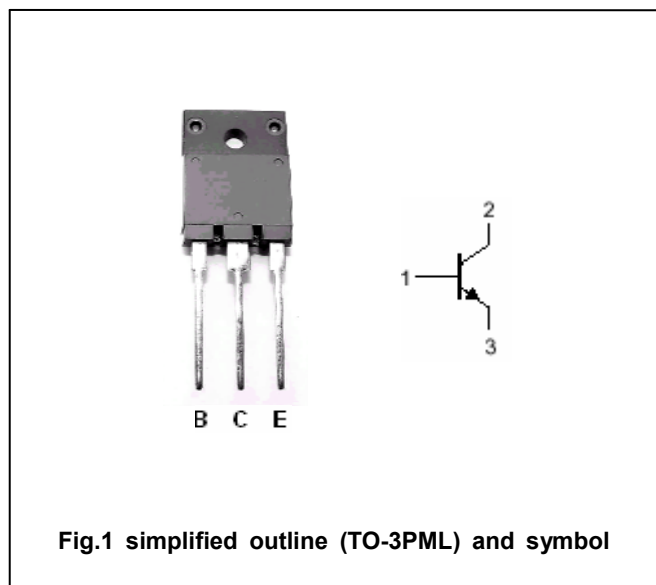
- With TO-3PML package
- Complement to type 2SA1909

**APPLICATIONS**

- Audio and general purpose

**PINNING**

PIN	DESCRIPTION
1	Base
2	Collector
3	Emitter

**Absolute maximum ratings(Tc=25°C)**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$V_{CBO}$	Collector-base voltage	Open emitter	200	V
$V_{CEO}$	Collector-emitter voltage	Open base	140	V
$V_{EBO}$	Emitter-base voltage	Open collector	6	V
$I_C$	Collector current		10	A
$I_B$	Base current		4	A
$P_C$	Collector power dissipation	$T_C=25^\circ\text{C}$	80	W
$T_j$	Junction temperature		150	°C
$T_{stg}$	Storage temperature		-55~150	°C

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## CHARACTERISTICS

T<sub>j</sub>=25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> =50mA; I <sub>B</sub> =0	140			V
V <sub>CEsat</sub>	Collector-emitter saturation voltage	I <sub>C</sub> =5 A; I <sub>B</sub> =0.5 A			0.5	V
I <sub>CBO</sub>	Collector cut-off current	V <sub>CB</sub> =200V ; I <sub>E</sub> =0			10	μA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> =6V; I <sub>C</sub> =0			10	μA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> =3A ; V <sub>CE</sub> =4V	50		180	
f <sub>T</sub>	Transition frequency	I <sub>E</sub> =-0.5A ; V <sub>CE</sub> =12V		20		MHz
C <sub>OB</sub>	Output capacitance	I <sub>E</sub> =0; V <sub>CB</sub> =10V; f=1MHz		250		pF

## Switching times

t <sub>on</sub>	Turn-on time	I <sub>C</sub> =5A; R <sub>L</sub> =12Ω I <sub>B1</sub> =-I <sub>B2</sub> =0.5A V <sub>CC</sub> =60V		0.24		μs
t <sub>s</sub>	Storage time			4.32		μs
t <sub>f</sub>	Fall time			0.40		μs

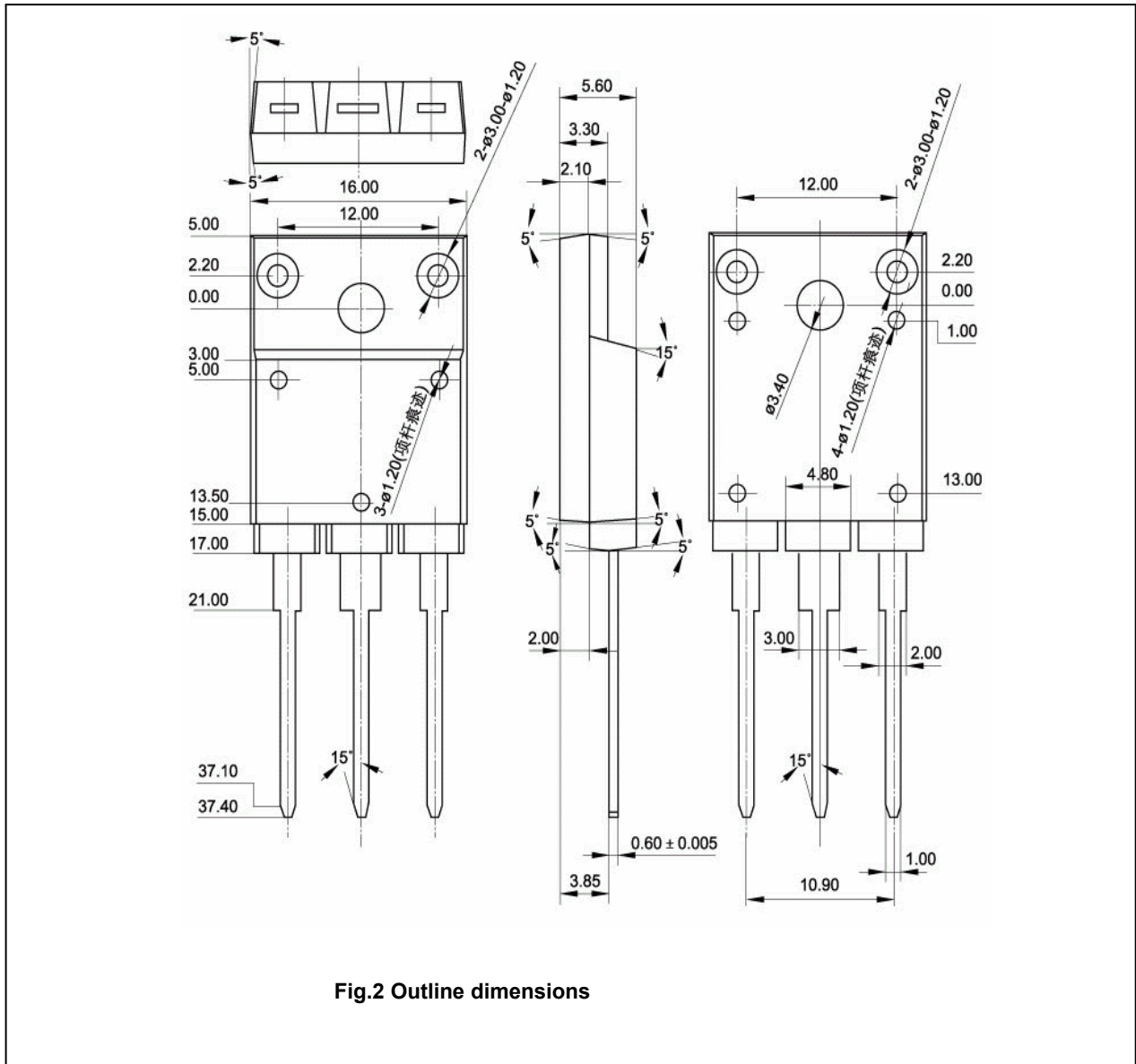
◆ h<sub>FE</sub> classifications

O	P	Y
50-100	70-140	90-180

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PACKAGE OUTLINE



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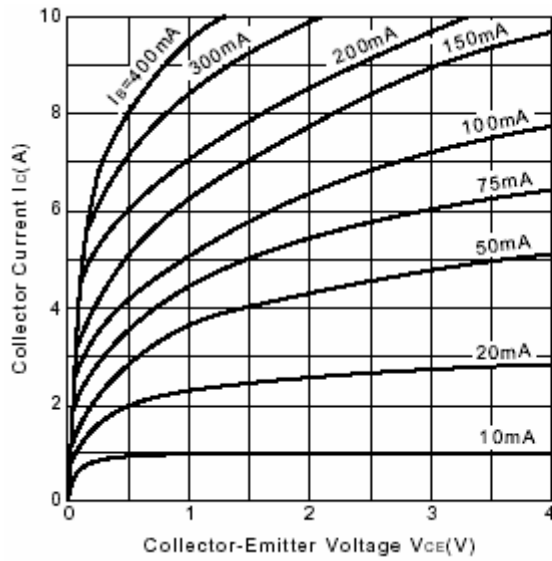


Fig.3 Static Characteristic

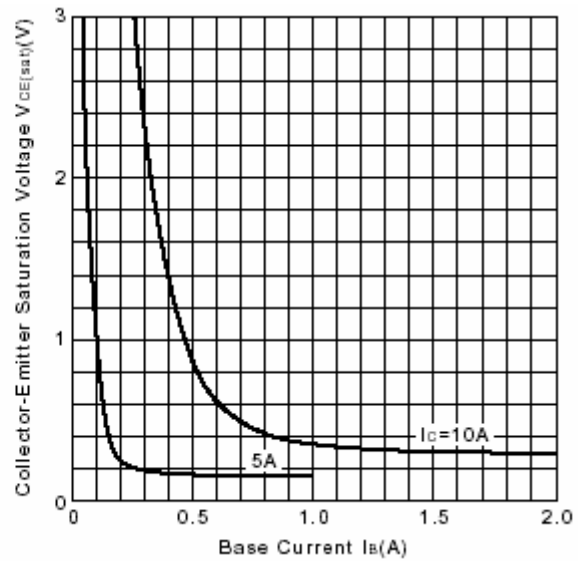


Fig.4  $V_{CE(sat)}$ - $I_B$  Characteristics

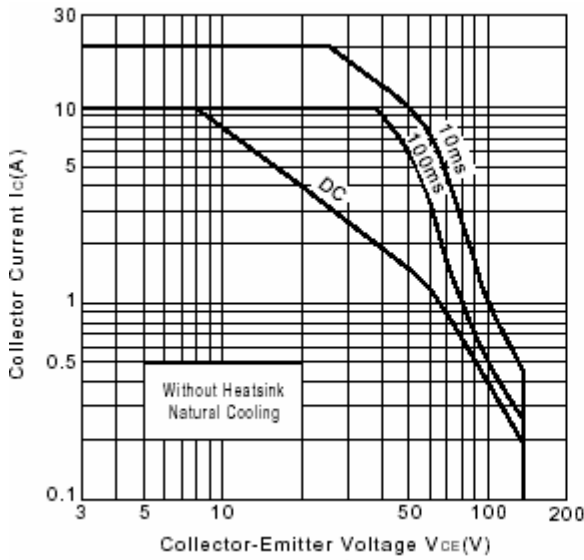


Fig.5 Safe Operating Area

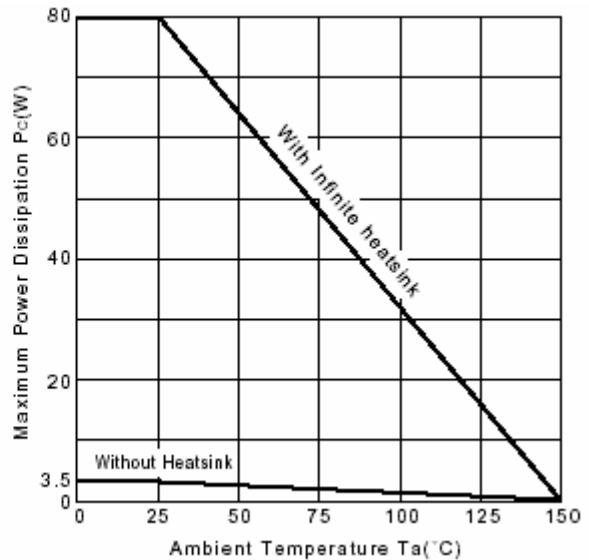


Fig.6  $P_c$ - $T_a$  Derating

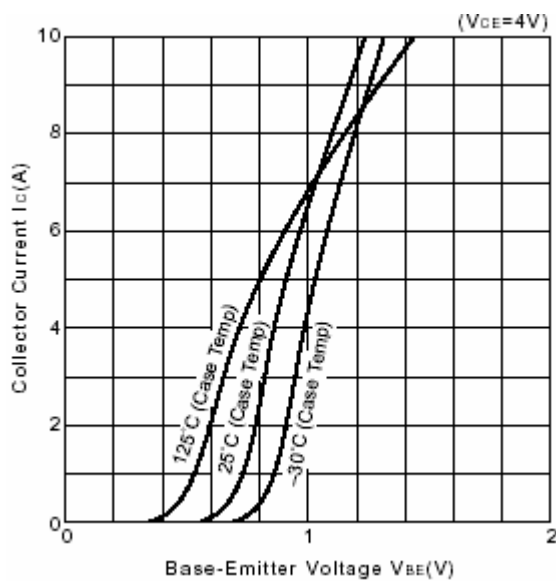


Fig.7  $I_C$ - $V_{BE}$

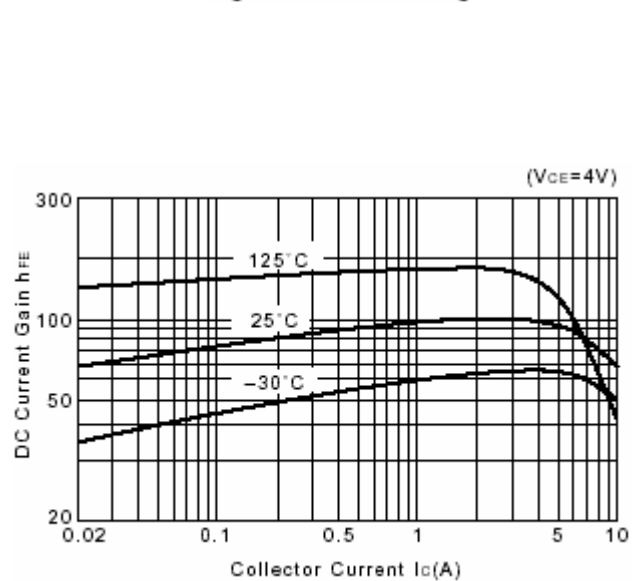


Fig.8 DC current Gain